

Search for Magnetism in HfO₂ Thin Films

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A recent intriguing report of the observation of unexpected and highly anisotropic ferromagnetism in the high- κ dielectric oxide HfO₂ thin films [1] has stirred the scientific community. If validated, this discovery of d^0 ferromagnetism in a transparent oxide undoubtedly represents a major advance for the field of spintronics [2]. Interestingly, the high- κ dielectric oxides such as HfO₂ are already under active consideration as gate dielectrics for next generation devices in semiconductor technology in view of the material compatibility with silicon [3]. Introducing a magnetic response in such dielectrics should enable an integration of complementary metal-oxide semiconductor (CMOS) with spintronic technology. The magnetic moment, derived from magnetization measurements, found by various groups in HfO₂ thin films is about 0.1 μ_B per formula unit.

From preliminary bulk studies [4] it was deduced that different muon states are present in HfO₂: μ^+ , $\text{Mu}_{\text{atomic}}^0$, and, for $T < 50\text{K}$, $\text{Mu}_{\text{shallow}}^0$. Differently to these findings, our preliminary low energy μSR (LE- μSR) study on HfO₂ thin films grown c-cut sapphire reveals a dominant μ^+ signal (derived from ZF/TF measurements). A pronounced two component depolarization in the whole measured temperature range ($T = 4 \dots 200\text{K}$) is observed. We attribute the fast depolarization as due to magnetism consistent with the macroscopic measurements (and not due to muonium depolarization/diffusion processes). We will discuss possible mechanisms which could lead to d^0 ferromagnetism.

[1] M. Venkatesan, C.B. Fitzgerald, and J.M.D. Coey, Nature 450 (2004) 630.

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[3] I. Žutić, J. Fabian, and S.D. Sarma, Rev. Mod. Phys. 76 (2004) 323.

[4] S.F.J. Cox et al., J. Phys.: Condens. Matter 18 (2006) 1079.